## NCV890231 Automotive Grade High-Frequency Buck Regulator Evaluation Board User's Manual

#### Description

The NCV890231 evaluation board provides a convenient way to evaluate a high-frequency buck converter design. No additional components are required, other than dc supplies for the input and enable voltages. An external clock can be used to synchronize the switching frequency; and the board also provides a synchronization output, enabling it to be used as a master. It is configured for a 3.3 V output with a 2 MHz switching frequency and a 2.0 A maximum output current, over the typical 4.5 V to 18 V automotive input voltage range. In addition, the board regulates up to 30 V thanks to switching frequency foldback.

## **Key Features**

- 3.3 V Output Voltage
- 2 MHz Switching Frequency
- 2.0 A Current Limit
- Wide Input Voltage of 4.5 V to 45 V
- Regulates through Load Dump Conditions
- External Clock Synchronization up to 2.5 MHz
- Synchronization Output
- Automotive Grade



Figure 1. NCV890231GEVB Board Picture



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## EVAL BOARD USER'S MANUAL

#### Table 1. DEMONSTRATION BOARD TERMINALS

Terminal	Function		
VIN	Positive dc input voltage		
GND	Common dc return		
VOUT	Regulated dc output voltage		
EN	Enable input		
SYNCI	Input for external clock synchronization		
SYNCO	Output for synchronizing other boards		

#### Table 2. ABSOLUTE MAXIMUM RATINGS

(Voltages are with respect to GND)

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Rating	Value	Units
Dc supply voltage (VIN, EN)	-0.3 to 45 V	V
Dc supply voltage (SYNCI)	-0.3 to 6 V	V
Junction Temperature (NCV890231)	-40 to 150	°C
Ambient temperature (Demo Board)	-40 to 85	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### Table 3. ELECTRICAL CHARACTERISTICS

 $(T_{A} = 25^{\circ}C, 4.5 \text{ V} \le V_{IN} \le 40 \text{ V}, V_{EN} = 2 \text{ V}, V_{OUT} = 3.3 \text{ V}, 0 \le I_{OUT} \le 2.0 \text{ A}, \text{ unless otherwise specified})$ Characteristics Conditions Typical Value Units

Characteristics	Conditions	Typical Value	Units		
Regulation					
Output Voltage		3.30	V		
Voltage Accuracy		4	%		
Line Regulation	I <sub>OUT</sub> = 1.0 A	0.12	%		
Load Regulation	V <sub>IN</sub> = 13.2 V	0.03	%		
Switching					
Switching Frequency		2.0	MHz		
Soft-start Time		1.4	ms		
SYNCI Frequency range		1.8 to 2.5	MHz		
Current Limit					
Average Current Limit	V <sub>IN</sub> = 6 to 18 V	1.8	А		
Cycle-by-cycle Current Limit		2.45	А		
Protections					
Input Undervoltage Lockout (UVLO)	V <sub>IN</sub> decreasing	4.2	V		
Thermal Shutdown	T <sub>A</sub> increasing	170	°C		



Figure 2. NCV890231GEVB Board Schematic

#### **Operational Guidelines**

- 1. Connect a dc input voltage, within the 4.5 V to 45 V range, between VIN and GND
- 2. Connect a load between VOUT and GND
- 3. Connect a dc enable voltage, within the 4.5 V to 40 V range, between EN and GND
- 4. Optionally, for external clock synchronization, connect a pulse source between SYNCI and GND. The high state level should be within the 2 to 6 V range, and the low state level within the -0.3 V to 0.8 V range, with a minimum pulse width of 40 ns and a frequency within the 1.8 to 2.5 MHz range.



Figure 3. NCV890231GEVB Board Connections

## **TYPICAL PERFORMANCE**











### Load Transients



Figure 7. Load transient 0.1 A to 2.0 A, with V\_{OUT} = 3.3 V and V\_IN = 13.2 V



Figure 8. Load transient 0.2 A to 2.0 A, with  $V_{OUT}$  = 3.3 V and  $V_{IN}$  = 13.2 V

Figure 9. Load transient 2.0 A to 0.2 A, with V<sub>OUT</sub> = 3.3 V and V<sub>IN</sub> = 13.2 V

## Synchronization



Figure 10. Starting synchronization at 2.5 MHz (from free-running)



Minimum on time

Figure 11. Minimum on time seen during a load transient

Schematic



## PCB LAYOUT



Figure 12. Top View



Figure 13. Bottom View

#### Table 4. BILL OF MATERIALS

Reference	Value	Part #	Manufacturer	Description	Package
U1		NCV890231	ON Semiconductor	Integrated circuit	3x3 DFN10
L1	4.7 μΗ	7447786004	Wurth	Inductor	WE-PD-XS
DFW		MBR440MFS	ON Semiconductor	Diode, Schottky, 1.5A, 40V	SMB
DBST		BAS16HT1	ON Semiconductor	I Semiconductor Diode, Switching, 200mA, 75V	
CVIN1	4.7 μF		Murata	Capacitor, Ceramic, 50V, X7R	1210
CVIN2	1 μF		Murata	Capacitor, Ceramic, 50V, X5R	0805
CDRV, CBST	0.1 μF		Kemet	Capacitor, Ceramic, 10V, X7R	0603
ZFB1	4.7 nF		Murata	Capacitor, Ceramic, 50V, X7R	0603
COUT1, COUT2	10 μF		Murata	Capacitor, Ceramic, 10V, X7R	1206
CCOMP	330 pF		Murata	Capacitor, Ceramic, 50V, C0G	0603
RCOMP	12.4 KΩ		Vishay	Resistor, 1%	0603
RFB1	100 Ω		Vishay	Resistor, 1%	0603
RFB2	31.6 Ω		Vishay	Resistor, 1%	0603